

- Designed for Complementary Use with the BD242 Series
- 40 W at 25°C Case Temperature
- 3 A Continuous Collector Current
- 5 A Peak Collector Current
- Customer-Specified Selections Available

# 

**TO-220 PACKAGE** 

Pin 2 is in electrical contact with the mounting base.

MDTRACA

#### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT
	BD241		55	
Collector-emitter voltage ( $R_{BE}$ = 100 $\Omega$ )	BD241A	\ \ <u>\</u>	70	V
	BD241B	V <sub>CER</sub>	90	٧
	BD241C		115	
	BD241		45	
Collector-emitter voltage (I <sub>C</sub> = 30 mA)	BD241A	V	60	V
	BD241B	V <sub>CEO</sub>	80	
	BD241C		100	
Emitter-base voltage			5	V
Continuous collector current			3	Α
Peak collector current (see Note 1)			5	Α
Continuous base current			1	Α
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			40	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W
Unclamped inductive load energy (see Note 4)			32	mJ
Operating junction temperature range			-65 to +150	°C
Storage temperature range			-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds			250	°C

NOTES: 1. This value applies for  $t_p \le 0.3$  ms, duty cycle  $\le 10\%$ .

- 2. Derate linearly to  $150^{\circ}\text{C}$  case temperature at the rate of  $0.32 \text{ W/}^{\circ}\text{C}$ .
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 0.4 A,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.



#### electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA (see Note 5)	I <sub>B</sub> = 0	BD241 BD241A BD241B BD241C	45 60 80 100			V
I <sub>CES</sub>	Collector-emitter cut-off current	$V_{CE} = 55 \text{ V}$ $V_{CE} = 70 \text{ V}$ $V_{CE} = 90 \text{ V}$ $V_{CE} = 115 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	BD241 BD241A BD241B BD241C			0.2 0.2 0.2 0.2	mA
I <sub>CEO</sub>	Collector cut-off current	V <sub>CE</sub> = 30 V V <sub>CE</sub> = 60 V	$I_{B} = 0$ $I_{B} = 0$	BD241/241A BD241B/241C			0.3 0.3	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0				1	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_C = 1 A$ $I_C = 3 A$	(see Notes 5 and 6)	25 10			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>B</sub> = 0.6 A	I <sub>C</sub> = 3 A	(see Notes 5 and 6)			1.2	V
$V_{BE}$	Base-emitter voltage	V <sub>CE</sub> = 4 V	I <sub>C</sub> = 3 A	(see Notes 5 and 6)			1.8	V
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.5 A	f = 1 kHz	20			
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.5 A	f = 1 MHz	3			_

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu s$ , duty cycle  $\leq 2\%$ .

#### thermal characteristics

PARAMETER			TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			3.125	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

#### resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t <sub>on</sub>	Turn-on time	I <sub>C</sub> = 1 A	$I_{B(on)} = 0.1 A$	$I_{B(off)} = -0.1 \text{ A}$		0.3		μs
t <sub>off</sub>	Turn-off time	$V_{BE(off)} = -3.7 \text{ V}$	$R_L = 20 \Omega$	$t_p = 20 \ \mu s, \ dc \le 2\%$		1		μs

<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>6.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

#### **TYPICAL CHARACTERISTICS**

# **TYPICAL DC CURRENT GAIN** vs **COLLECTOR CURRENT** TCS631AH 1000 V<sub>CE</sub> = 4 V = 25°C $t_p = 300 \mu s$ , duty cycle < 2%T<sub>C</sub> = 80°C h<sub>FE</sub> - DC Current Gain 100 10 0.01 0.1 1.0 10 I<sub>c</sub> - Collector Current - A

Figure 1.

**COLLECTOR-EMITTER SATURATION VOLTAGE** 

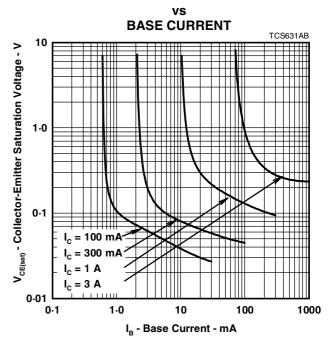


Figure 2.

#### BASE-EMITTER VOLTAGE

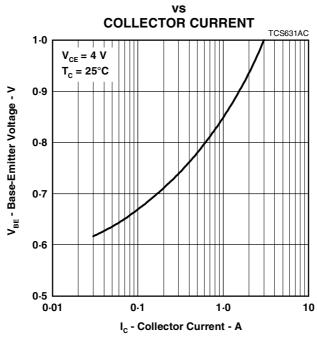
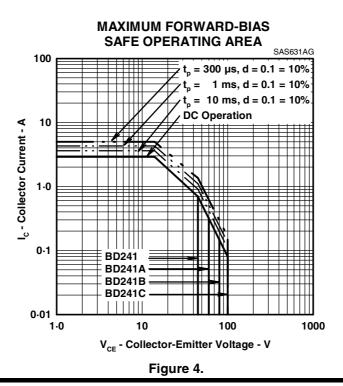


Figure 3.

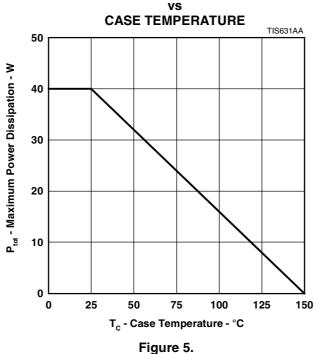
#### PRODUCT INFORMATION

#### **MAXIMUM SAFE OPERATING REGIONS**



#### THERMAL INFORMATION

### MAXIMUM POWER DISSIPATION



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